

## **KSD526**

## **Power Amplifier Applications**

Complement to KSB596



1.Base 2.Collector 3.Emitter

# **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	80	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	4	Α
I <sub>B</sub>	Base Current	0.4	Α
P <sub>C</sub>	Collector Dissipation ( T <sub>C</sub> =25°C)	30	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

### **Electrical Characteristics** $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 80V, I_{E} = 0$			30	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			100	μΑ
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = 50 \text{mA}, I_B = 0$	80			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10 \text{mA}, I_C = 0$	5			V
h <sub>FE1</sub>	DC Current Gain	$V_{CE} = 50V, I_{C} = 0.5A$	40		240	
h <sub>FE2</sub>		$V_{CE} = 5V, I_{C} = 3A$	15	50		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 3A, I_B = 0.3A$		0.45	1.5	V
V <sub>BE</sub> (on)	Base-Emitter ON Voltage	$V_{CE} = 5V, I_{C} = 3A$		1	1.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 0.5A$	3	8		MHz
C <sub>ob</sub>	Collector Output Capacitance	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$		90		pF

## **h**FE Classification

Classification	R	0	Υ
h <sub>FE</sub>	40 ~ 80	70 ~ 140	120 ~ 240

# **Typical Characteristics**

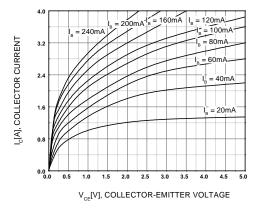


Figure 1. Static Characteristic

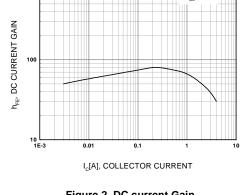


Figure 2. DC current Gain

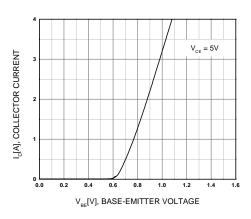


Figure 3. Base-Emitter On Voltage

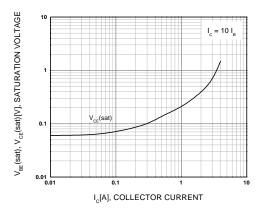


Figure 4. Collector-Emitter Saturation Voltage

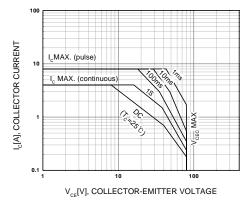


Figure 5. Safe Operating Area

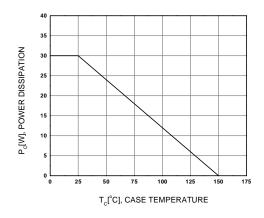
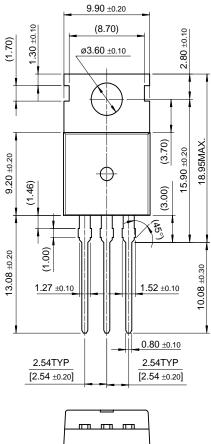


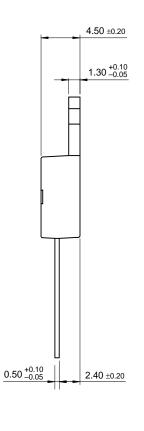
Figure 6. Power Derating

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# **Package Demensions**

# TO-220





10.00 ±0.20

Dimensions in Millimeters

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